The Kukhtarev equations are solved taking into account the photovoltaic effect and different boundary conditions. In the case of open circuit, the voltage across the crystal is found to vary with a time scale similar to the photorefractive time constant. This effect explains the dynamic behavior observed experimentally.

I. INTRODUCTION

Photorefractive crystals have become increasingly important as candidate media for the realization of many optical information processing systems including mass memory, neural network implementations, and signal processors. Photorefraction in electro-optic crystals is well understood in terms of the band transport model which describes it in terms of the following processes: (1) the photo-excitation of charged carriers from impurities by a nonuniform intensity pattern, (2) charge transport mechanisms (diffusion, drift, photovoltaic) which move these charges in the conduction band to empty trap sites where they are captured, creating a nonuniform space-charge field, and (3) nonuniform modulation of the index of refraction via the electro-optic effect.

Among the various transport mechanisms, the photovoltaic effect, in which a short-circuit current (or, equivalently, an open-circuit voltage) is generated by illumination of the crystal with light, has been observed only in a few ferroelectric crystals such as LiNbO₃ and KNbO₃. Although the photovoltaic effect is accounted for in the Kukhtarev equations, a transient theory that includes the effects due to the boundary conditions (e.g., open- or short-circuited crystal) has not yet been formulated. LiNbO₃ which can be used for long-term memory storage applications due to its low dark conductivity, exhibits a particularly large photovoltaic effect, and such a theory may prove to be useful for further application developments. In this paper, we solve the Kukhtarev equations taking into account various possible boundary conditions to describe the growth and decay of holograms in photovoltaic media. We then give theoretical plots describing the transient behavior of holograms using published values of parameters for LiNbO₃. The experimental results, showing different dynamic behaviors during grating formation for different boundary conditions, are then compared with the theoretical calculation. Both experimental result and theoretical simulation show the typical behavior of grating formation which does not occur in nonphotovoltaic media, i.e., when the writing starts from an open-circuited crystal without nonuniform charge distribution, the diffraction efficiency increases to a maximum value then decreases to reach its steady state.

II. FORMATION OF GRATINGS WITH APPLIED FIELD

The dynamic behavior of the photorefractive effect is described by the following set of nonlinear coupled equations:

$$\frac{\partial N_D^+}{\partial t} = (N_D - N_D^+) (sI + \beta) - \gamma_R N_D^+ n, \quad (1)$$

$$\frac{\partial n}{\partial t} = \frac{\partial J}{\partial x} + e \frac{\partial E}{\partial x}, \quad (2)$$

$$J = e \mu n E + k_B T \mu \frac{\partial n}{\partial x} + p (N_D - N_D^+) I, \quad (3)$$

$$\epsilon \frac{\partial E}{\partial x} = e (N_D^+ - n - N_A), \quad (4)$$

where $N_D$, $N_D^+$, $n$, $N_A$ are densities of traps, ionized traps, charged carriers (electrons in the conduction band) and compensative acceptors, respectively, $I$ is the optical intensity in the crystal, $\beta$ is the thermal generation rate, $s$ is the photoexcitation cross section, $\mu$ is the carrier mobility, $e$ is the electronic charge, $\gamma_R$ is the carrier recombination rate constant, $\epsilon$ is the dielectric constant of the crystal, $E$ is the total electric field inside the crystal, and $p$ is the photovoltaic constant. The photovoltaic term in Eq. (3) depends on the nonionized trap density because the photovoltaic current is proportional to the photoabsorption constant which in turn depends on the nonionized trap density. In the special case of $N_D^+ \ll N_D$, we can write this term as a constant times the intensity and is equivalent to eliminating all the terms containing density ratios $N_A/N_D$ in the final results. In this paper, we will include the $(N_D^+ - N_D^0)$ term explicitly. Following the standard procedure of linearization, which is legitimate for small modulation depth, we assume the following forms for the various physical quantities:

$$N_D^+ = N_D^0 + \delta N_D^+, \quad \delta n = n_0 + \delta n,$$

$$n = n_0 + \delta n,$$
\[ J = J_0 + \delta J, \]  
\[ E = E_0 + \delta E, \]  
and then solve the coupled equations (1)–(4) for the zero- 
and first-order terms with an intensity given by
\[ I = I_0(1 + m \cos Kx), \]  
where \( m \) is the modulation depth of the grating, and \( K \) is 
the grating wave vector. The small modulation depth re-
quires that \( m \ll 1 \). Notice that when \( m = 0, E = E_0 \). In 
other words, \( E_0 \) is the dc component of the spatial Fourier 
transform of \( E \). \( N_{\delta 0} \) and \( n_0 \) change very rapidly towards 
their steady-state values, compared to the rate at which the 
spatially varying components change. Therefore, we 
solve the set of equations (1)–(4) by first calculating the 
steady-state values for \( N_{\delta 0} \) and \( n_0 \) and then using these as 
constants to solve for the temporal evolution of \( \delta E \). In 
addition, we make the following assumptions: (1) \( \beta \ll 1 \), 
(2) \( n_0 \ll N_A \), and (3) \( n_0 \ll \gamma R N_A \).

Under these conditions, the zero-order terms can be 
obtained as
\[ N_{\delta 0} = N_A, \]  
\[ n_0 = \frac{(N_D - N_A) n_0}{\gamma R N_A}. \]  
In order to proceed with the calculations of the first-order 
perturbation terms in Eqs. (5)–(8), we need to apply the 
appropriate boundary conditions so that the zero-order 
electric field \( E_0 \) can be determined. In this section, we ex-
amine the case of a constant applied field so that the term 
\( E_0 \) in Eq. (8) is equal to the externally applied electric 
field.

Substituting these zero-order terms along with Eqs. 
(5)–(9) into the linearized Kukhtarev equations, we ob-
tain a set of linear partial differential equations with con-
stant coefficients. The equations can then be solved and the 
solution for the space-charge field is given by
\[ \delta E = m E_{\omega} \left[ - \cos(Kx + \psi) + \exp(-t/\tau) \cos(Kx + \omega_g t + \psi) \right], \]  
where the amplitude \( E_{\omega} \) is given by
\[ E_{\omega} = \left[ \frac{(E_0 - E_{\omega ph})^2 + E_D^2}{[E_0 - (N_{\delta 0}/N_D)E_{\omega ph}]^2 + (E_D + E_\mu)^2} \right]^{1/2}, \]  
and the phase of the grating is given by
\[ \tan \psi = \frac{(E_D + E_\mu) \omega_g + E_\mu}{(E_D + E_\mu) \omega_g - E_\mu} \frac{(E_D + E_\mu) E_\mu + (E_0 - E_{\omega ph})}{(E_0 - E_{\omega ph}) E_\mu - E_{\omega ph}} \frac{E_\mu}{(N_D - N_A)/N_D}. \]  

In arriving at these results, we have made use of the fol-
lowing expressions, in respective order, for the time con-
stant, oscillatory frequency, dielectric relaxation time, dif-
fusion field, saturation field, drift field, and photovoltaic 
field:
\[ \tau = \tau_d \left[ \frac{1 + (E_D/E_{\mu})^2}{1 + (E_D/E_{\mu})^2 + (E_\mu/E_\mu)^2} \right] \]  
\[ \omega_g = \frac{E_\mu - (E_0/E_\mu) - (N_{\delta 0}E_{\omega ph}/N_D E_\mu) \frac{1 + (E_D/E_\mu)}{[1 + (E_D/E_\mu)]^2 + (E_\mu/E_\mu)^2}, \]  
\[ \tau_d = \frac{e \mu n_0}{e K T}, \]  
\[ E_D = k_B T K/e, \]  
\[ E_\mu = \frac{e N_A(N_D - N_A)}{e K N_D}, \]  
\[ E_{\omega ph} = (\gamma R N_{\delta 0}/e \mu S). \]  

Several qualitative results need to be noted here. First, the 
photovoltaic effect cannot be thought of as an equivalent 
applied field since the above expressions for the phase, time 
constant, and oscillatory frequency of the grating do not 
depend on a single linear combination of \( E_0 \) and \( E_{\omega ph} \). The 
oscillatory frequency \( \omega_g \) gives rise to ringing during the 
formation of the grating even in the absence of an external 
field, according to Eq. (16). In the limiting case of no 
photovoltaic effect (i.e., \( p = 0 \)), these solutions reduce to 
previous results.\(^{11}\)

**III. GRATING FORMATION UNDER OPEN-CIRCUIT 
BORDER CONDITION**

The experimental configuration most widely used is 
the open-circuit condition. In this case, photovoltaic crys-
tals will develop an open-circuit voltage upon illumination 
whose time scale is similar to the photorefractive time con-
stant. We need to evaluate the growth of the dc field 
\( E_0(t) \), now a function of time, before we calculate the 
space-charge field.

The dc field \( E_0(t) \) can be obtained by introducing a 
surface charge density \( \sigma(t) \) at the ends of the crystal\(^7\) as 
illustrated in Fig. 1(a). The use of a surface charge distri-
bution is justified by experimentally observing the macro-
scopic charge distribution that results when we uniformly
FIG. 1. (a) Open-circuit crystal (shows surface charge). (b) Interference fringes showing the index change of a partially illuminated crystal. The c axis is parallel to the fringes, and the probe beam is extraordinarily polarized.

Because of this time variation in the zero-order field, the linearized Kukhtarev equations now have time-varying constants. We write the space-charge field as

$$\delta E(t) = E_0(t) \exp(iKx) + c.c. \quad (25)$$

Substituting the above in the Kukhtarev equations and neglecting terms containing $d^2 E_1/dt^2$, we arrive at the following differential equation for $E_1$:

$$\frac{dE_1}{dt} = -\frac{1}{\tau_d} [a(t)E_1 + b(t)E_2], \quad (26)$$

where the time-varying constants are

$$a(t) = \frac{1 + \{E_D/E_2]\} - i\{E_0[1 - \exp(-t/\tau_d)]/E_2]\}}{1 + \{E_D/E_2\} - i\{E_0[1 - \exp(-t/\tau_d)]/E_2\]}, \quad (27)$$

$$b(t) = \frac{(m/2)[ - (E_D/E_2) \exp(-t/\tau_d) + i\{E_D/E_2]\}}{1 + \{E_D/E_2\} - i\{E_0[1 - \exp(-t/\tau_d)]/E_2\}]. \quad (28)$$

In deriving the above expressions, we have assumed $N_d \ll N_p$ for simplicity.

Before discussing the theoretical solution, we first present experimental results showing the striking differences in the diffraction efficiency during hologram growth for two different boundary conditions: (1) open circuit, (2) steady voltage. The open-circuit boundary condition is most easily achieved, as shown in Fig. 2(a), by writing a hologram whose overall transverse dimensions are smaller than the crystal dimensions (this is not really necessary but most easily achievable experimentally), so that the surface charge introduced earlier actually develops within the bulk of the crystal at the boundary between the illuminated and dark regions. After this experiment is performed, the hologram is carefully erased with a third beam which is not Bragg-matched to the written grating but illuminates only (approximately) the region where the grating exists, as shown in Fig. 2(b). The grating is thus erased but the open-circuit electric field remains across the region where the hologram was written. Now, the same grating can be written again in the same area under new boundary conditions imposed by the steady dc field developed in the previous exposure, provided the field remains.

The LiNbO$_3$ crystal (0.015% Fe doped; 18 mm X 18 mm X 8 mm:xyz) was antireflection coated on the broad faces. The apparatus for writing holographic gratings and monitoring their diffraction efficiencies is shown in Fig. 3. An argon laser ($\lambda = 0.5145 \mu m$) supplied the two writing beams (76.45 and 1.47 mW, 0.9-1 mm radius) which were both ordinary polarized to minimize beam coupling effects during recording and directed to write gratings whose orientation is parallel to the crystal c axis (i.e., grating planes perpendicular to the c axis, external angle between the two beams: 16'). A He-Ne laser ($\lambda = 0.633 \mu m$) supplied the reading beam (43 $\mu W$) which was extraordinary polarized to access the large $r_{33}$ electro-optic coefficient. After writing a grating and carefully adjusting the reading beam to satisfy the Bragg condition, the writing beam was shut off, and the crystal was translated to a new position where
gratings were not previously written ("fresh location") to perform the open-circuit boundary condition experiment. The writing beams were turned on and the growth of the hologram was monitored with the reading beam. The growth characteristics of the grating is shown in the lower trace in Fig. 4(a) where the grating is shown to peak initially and decrease to a smaller steady state value. Such a result was observed by earlier works but attributed to nonlinear beam coupling effects. In our experiment, the beam coupling was also monitored by recording the intensity of one of the writing beams (the pump, in two wave mixing language which is also shown in Fig. 4(a) (the upper trace). Apparently, there is very little pump depletion throughout the trace, hence beam coupling effects are not significant.

Next by optically erasing the previously written grating (power of the erasing beam: 525 mW), an experiment to monitor grating development for the steady applied electric field was set up (power of the two writing beams: 76.45 and 150 mW); the steady applied electric field is, as discussed previously, the open-circuit field that is set up by the photovoltaic effect created in the last exposure.
monitored diffraction efficiency is shown in Fig. 4(b), where, again, the beam coupling that was monitored was minimal. Note the strikingly different behavior in the two boundary conditions.

We now compare the observed results with our theoretical solutions. Eq. (26) is most easily solved numerically. In order to do this, we make use of several published parameters for Fe-doped LiNbO₃, $\mu \tau = 1.6 \times 10^{-12} \text{cm}^2/\text{V}$ and $|E_{\text{ph}}| = 4.5 \text{KV/cm}$ measured earlier for the particular crystal used in our experiment. Other parameters are estimated by fitting the experimental writing curve [Fig. 4(a)]. In Eqs. (18)-(21), the grating wave vector $K$ can be calculated from the external angle between the two writing beams ($16^\circ$), $T$ can be taken approximately as
room temperature (300 K), and the unknown parameters are \( N_A \) and \( N_D \). We can adjust these two variables to fit the general shape of Fig. 4(a). The parameters we used for plotting Fig. 5(a) are as follows: 

\[
N_A \approx 2 \times 10^{16} \text{cm}^{-3}, \quad N_D \approx 4 \times 10^{17} \text{cm}^{-3}, \quad m = 0.272, \quad E_D = 0.88 \text{ kV/cm}, \quad E_p = 1.8 \times 10^4 \text{ kV/cm}, \quad E_q = 33 \text{ kV/cm}, \quad \text{and } \Lambda = 1.85 \mu\text{m}.
\]

We now solve Eq. (26) using the fifth-order Runge-Kutta method\(^\text{13}\) with adaptive step size. Since there are more than one unknown parameter, we do not attempt to fit the experimental curve quantitatively, but the qualitative fit of the experimental result to theory is good.

In Fig. 5(b), we compare the diffraction efficiencies for different boundary conditions. It can be noticed, in the case of open circuit \((E_0 = \text{function of time})\), the beginning of the gratings formation is the same as that in the case of short circuit \((E_0 = 0)\). The steady-state diffraction efficiencies of the open-circuit case with \(E_0\) a function of time and \(E_0 = E_{\text{opt}}\) asymptotically converge. Between the beginning and the steady state, the diffraction efficiency reaches a maximum, then decreases to a constant. We can also notice that the steady-state diffraction efficiency of the short-circuit case is higher than that of the open-circuit case.

IV. CONCLUSION

We have theoretically explained the unique dynamic behavior of grating formation in photovoltaic media taking into account the time variation of the spatially uniform field across the crystal. Due to the photovoltaic effect, the dynamics of grating formation depends on the Initial condition as well as the boundary condition. This effect causes a problem when we attempt to find an exposure procedure for the recording of multiple holograms. The results in this paper suggest that one simple solution might be to short circuit the crystal, since in this case the steady-state diffraction efficiency is higher than others and the initial condition remains the same for all exposures. However, more careful investigations of the boundary conditions that are established when a crystal is shortened may be necessary in order to accomplish the desired response in practice.

\(^{7}\) J. Hong, S. Campbell, and P. Yeh, Proc. SPIE 1151, 56 (1989).
\(^{13}\) See, for example, P. Yeh, Proc. SPIE 1151, 56 (1989).